August 2015

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1.0A SURFACE MOUNT SCHOTTKY BRIDGE

Product Summary

V _{RRM} (V)	I _O (A)	V _F Max (V) @ +25°C	I _R Max (mA) @ +25°C	
30	1	0.42	1	

Features

- Low profile package, ideal for thin portable applications
- Low forward voltage drop reduces power dissipation
- Soft switching characteristic ensures that EMI and EFI are minimized
- Guard ring die construction for transient protection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Description

Packaged in the compact DFN5060-4 the SDM1L30BLP is designed with low forward voltage and soft switching characteristics to meet the needs of wireless charging applications.

Mechanical Data

- Case: V-DFN5060-4
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (2)
- Polarity: See Diagram
- Weight: 0.0715 grams (Approximate)

1 2

Top View Device Schematic

V-DFN5060-4





Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
SDM1L30BLP-13	V-DFN5060-4	3.000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



SSD3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C =2015) M = Month (ex: 9 = September)

Date Code Key

Year	201	4	2015		2016	20	17	2018		2019	2	2020
Code	В		С		D		Ε	F		G		Н
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	4	2	2	1	5	6	7	Q	0	0	N	٦



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	30	V
Average Rectified Output Current	Io	1.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (Per Diode)	I _{FSM}	50	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5)	$R_{ heta JC}$	15	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

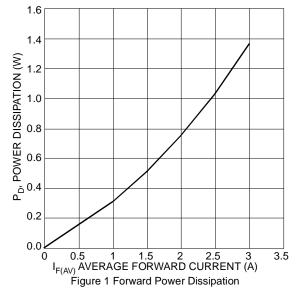
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop (Per Diode)	VF		0.21 0.31	— 0.42	V	I _F = 0.1A, T _J = +25°C I _F = 1.0A, T _J = +25°C
Leakage Current (Note 6) (Per Diode)	I _R	_	_	1.0	mA	$V_R = 30V, T_J = +25^{\circ}C$
Total Capacitance	Ст	ı	90	_	pF	$V_R = 30V, f = 1.0MHz,$ $T_J = +25^{\circ}C$

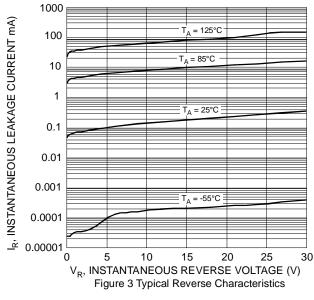
Notes:

^{5.} Device mounted on Polymide PCB with 1x recommended pad layout, with minimum recommended pad layout per http://www.diodes.com.

^{6.} Short duration pulse test used to minimize self-heating effect.







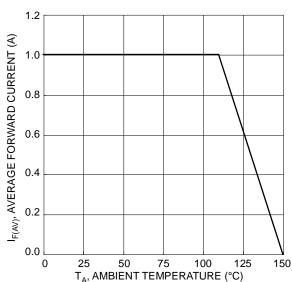
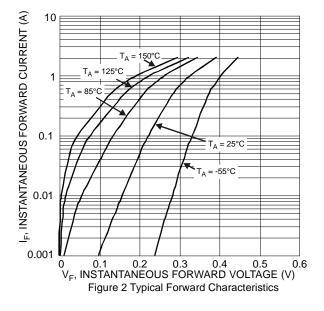


Figure 5 Forward Current Derating Curve



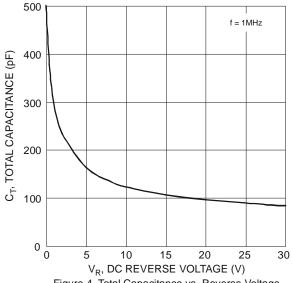


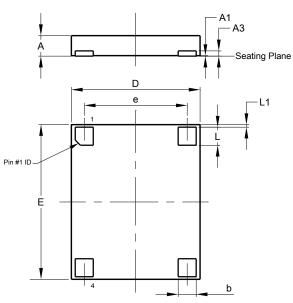
Figure 4 Total Capacitance vs. Reverse Voltage



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

V-DFN5060-4

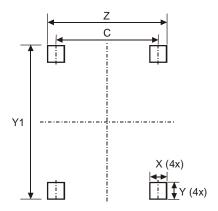


V-DFN5060-4						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0	0.05	0.02			
A3	_	_	0.203			
b	0.65	0.75	0.70			
D	4.95	5.05	5.00			
е	-	_	4.00			
Е	5.95	6.05	6.00			
L	0.65	0.75	0.70			
L1	0.05	0.15	0.10			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

V-DFN5060-4



Dimensions	Value (in mm)
С	4.00
Х	0.75
Υ	0.95
Y1	6.20
7	4 75



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